

1ch Low Side Switch IC In-Vehicle 1ch Low Side Switch

BD1LB500 Series (BD1LB500EFJ-C BD1LB500FVM-C)

Features

- Built-in overcurrent limiting circuit
- Built-in thermal shutdown circuit (TSD)
- Built-in open load detection circuit (at output OFF)
- Enables direct control from CMOS logic ICs, etc.
- Low standby current
- Built-in under voltage lock out circuit
- Built-in diagnostic output (ST) terminal
- Low ON resistance R_{DS(ON)}=350mΩ(Typ) (V_{DD}=IN=5V, Ta=25°C, I_{OUT}=0.25A)
- Built-in overvoltage protection(active clamp) for output circuit
- Monolithic power IC in which the control unit (CMOS) and power MOS FET are incorporated into one chip
- 1ch low side switch for driving mechanical relay coil
 AEC-Q100 Qualified⁽¹⁾
 - (1) Grade1

Overview

BD1LB500 Series is an in-vehicle 1ch low side switch. This switch builds in the overcurrent limiting circuit, thermal shutdown circuit, open load detection circuit and under voltage lock out circuit. It also provides the diagnostic output circuit when an abnormality is detected.

Application

 In-vehicle application (Air conditioners, body devices, meters, etc.)

Basic Application Circuit (Recommendation)

Specifications

Operating voltage range	3.5V to 5.5V
ON resistance (25°C, Typ.)	350mΩ
Overcurrent limitation (Typ.)	1.50A
Active clamp energy (25°C)	25mJ

Package

HTŠOP-J8 MSOP8

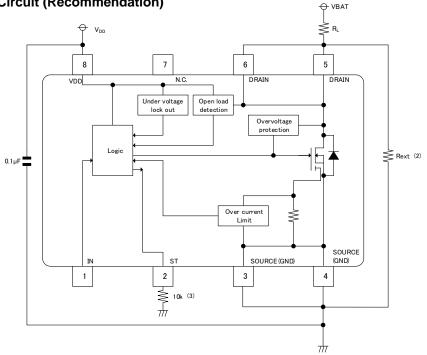
4.90mm x 6.00mm x 1.00mm 2.90mm x 4.00mm x 0.90mm





HTSOP-J8

MSOP8



- (2) When the open detection function is required, an external resistance must be added between DRAIN terminal and SOURCE terminal.
- (3) It is necessary to detect unusual state(ST terminal is low) when VDD terminal is opened. When ST pin is not used, it can be open.

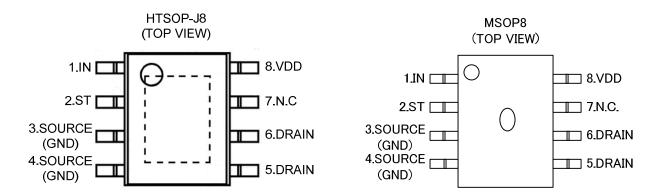
OProduct configuration: Silicon monolithic integrated circuit OThe product is not designed for radiation resistance.

Pin Descriptions

Pin No.	Symbol	Function
1	IN	Input terminal; a pull down resistor is connected internally.
2	ST	Self-diagnostic output terminal; outputs "L" at detection of overcurrent, at open (IN=0V), and in the overheat state. See the truth table. It is structured as COMS inverter output circuit.
3,4	SOURCE (GND)	Ground terminal
5,6	DRAIN	Output terminal; limits output current to protect IC when load is short-circuited and current exceeding the overcurrent detection value (0.8A Min) flows to the output terminal.
7	N.C.	No Connect pin
8	VDD	Power supply terminal
Cooling Tab (1)	TAB	The heat radiation metal on the substrate is connected to the IC sub. Therefore, connect Cooling Tab to the external GND electrical potential (for HTSOP-J8 only).

(1)MSOP8 does not have Cooling Tab.

Pin Configurations



Product Name	PKG	TSD function	ON resistance (25°C,Typ)
BD1LB500EFJ-C	HTSOP-J8	Self-restart	250m0
BD1LB500FVM-C	MSOP8	Sen-restart	350mΩ

Absolute Maximum Ratings

Item	Symbol	Limit values	Unit
DRAIN-SOURCE voltage	Vds	42 (internally limited)	V
Power supply voltage	Vdd	7	V
Diagnostic output voltage	V _{ST}	-0.3 to +7 ⁽¹⁾	V
Output current (DC)	lod	0.8 (2)	А
Output current (Pulse)	Іор	Internally limited ⁽³⁾	А
Input voltage	VIN	-0.3 to +7 ⁽¹⁾	V
Dewer concumption	Pd	2.1(HTSOP-J8) ⁽⁴⁾	w
Power consumption	Pu	0.587(MSOP8) ⁽⁵⁾	vv
Operating temperature range	T _{opr}	-40≤T _{opr} <+150	°C
Storage temperature range	T _{stg}	-55 to +150	°C
Maximum junction temperature	Tjmax	150	°C
	EAS(25°C)	25 ⁽⁶⁾	mJ
Active clamp energy (single pulse)	E _{AS(150°C)}	25 ⁽⁷⁾⁽⁸⁾	mJ

Operating Voltage Ratings

Item	Code	Limit values	Unit
Operating voltage range	Vdd	3.5 to 5.5	V

(1) The condition, $V_{\text{DD}}\!>\!V_{\text{IN}},\,V_{\text{ST}}$ is required.

(2) The value must not exceed Pd.

(3) Internally limited by the overcurrent limiting circuit.

(4) When mounting PCB (70×70[mm], thickness 1.6[mm], copper foil area 70×70[mm], glass epoxy 2-layer substrate).

When using at Ta ≥ 25°C, power dissipation is reduced at 16.8mW/°C.

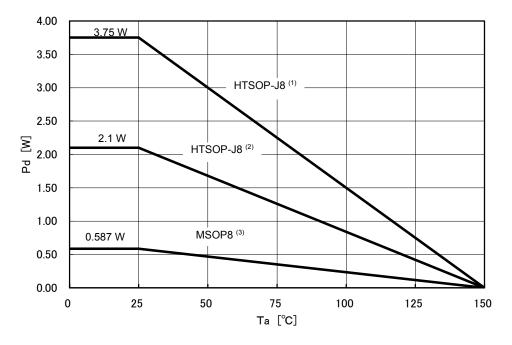
(5) When mounting PCB (70×70[mm], thickness 1.6[mm], copper foil area is Footprint only, glass epoxy single-layer substrate). When using at Ta ≥ 25°C, power dissipation is reduced at 4.7mW/°C.

(6) Active clamp energy at $T_{i(0)} = 25^{\circ}$ C, using single non-repetitive pulse of 0.4A

(7) Active clamp energy at $T_{j(0)} = 150^{\circ}$ C, using single non-repetitive pulse of 0.4A

(8) Not 100% tested.

Heat Dissipation Characteristics



(HTSOP-J8) (1) When mounting PCB (70×70[mm], thickness 1.6[mm], copper foil area 70×70[mm], glass epoxy 4-layer substrate) When using at Ta ≥ 25°C, power dissipation is reduced at 30mW/°C. (2) When mounting PCB (70×70[mm], thickness 1.6[mm], copper foil area 70×70[mm], glass epoxy 2-layer substrate) When using at Ta ≥ 25°C, power dissipation is reduced at 16.8mW/°C.

(MSOP8) (3) When mounting PCB (70×70[mm], thickness 1.6[mm], copper foil area is Footprint only, glass epoxy single-layer substrate)

When using at Ta \geq 25°C, power dissipation is reduced at 4.7mW/°C.

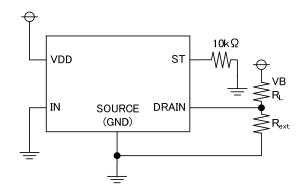
Electrical Characteristics (V_{DD}=3.5V to 5.5V, -40°C \leq T_j \leq +150°C unless otherwise is specified)

Item	Symbol	Limit values		Unit	Condition	
llem	Symbol	Min	Тур	Max		Condition
[Power Supply Block]						
Standby current	IDDS	_	0	10	μA	V _{DD} =5V,V _{IN} =0V,V _B =12V,R _L =47Ω
Operating current	Idd	_	0.5	1.0	mA	V _{DD} =5V,V _{IN} =5V,V _B =12V,R _L =47Ω
Under voltage lock out threshold voltage	V _{UVLO}	_	2.5	3.0	V	
[Input Block]						
H level input voltage	V _{TH1}	_	_	V _{DD} ×0.8	V	
L level input voltage	V _{TH2}	V _{DD} ×0.2	_	_	V	
Input hysteresis	V _{HYS}	_	0.40	_	V	
High level input current	I _{INH1}	_	50	100	μA	V _{IN} =5V
Low level input current	Iinl	-1	0	1	μA	V _{IN} =0V
[Power MOS output]			L	<u> </u>	1	
	R _{DS(ON)}	_	350	450	mΩ	V _{IN} =5V, V _{DD} =5V,I _D =0.25A,Tj=25°C
Output ON resistance	R _{DS(ON)}	_	570	750	mΩ	V _{IN} =5V, V _{DD} =5V,I _D =0.25A,Tj=150°C
	I _{L(OFF)}	_	_	10	μA	V _{IN} =0V,V _{DS} =12V,Tj=25°C
Output leak current	I _{L(OFF)}	_	_	100	μA	V _{IN} =0V,V _{DS} =12V,Tj=150°C
Cuitabing time	ton	_	20	40	μs	V_{DD} =5V, V_{IN} =0V/5V, RL=47 Ω
Switching time	toff	_	20	40	μs	V_{DD} =5V, V_{IN} =0V/5V, RL=47 Ω
Slew rate (at ON)	dV/dton	0.5	1	2	V/µs	V_{DD} =5V, V_{IN} =0V/5V, RL=47 Ω
Slew rate (at OFF)	-dV/dtoff	0.5	1	2	V/µs	V_{DD} =5V, V_{IN} =0V/5V, RL=47 Ω
Output clamp voltage	VcL	42	47	52	V	V _{IN} =0V,I _{OUT} =-1mA
[Diagnostic output]	1		1			
Diagnostic output voltage "L level"	V _{STL}	_	_	0.4	V	V_{DD} =5V, V_{IN} =5V, I_{ST} =0.1mA
Diagnostic output voltage "H level"	Vsth	4.88	_	_	V	V _{DD} =5V,V _{IN} =0V,I _{ST} =-0.1mA
Diagnostic output current "H level"	Isth	_	_	10	μA	V _{IN} =0V,V _{ST} =5.5V

Electrical Characteristics (V_{DD}=3.5V to 5.5V, -40°C≤ Tj≤ +150°C unless otherwise is specified)

			-			
Item	Symbol		Rated value		Unit	Condition
liem	Symbol	Min	Тур	Max	Offic	Condition
[Protective circuit]						
Overcurrent detection current	IOCP	0.8	1.5	2.5	А	V _{IN} =5V
Diagnostia output dolov timo	t DHL	_	40	80	μs	V _{DD} =5V,R _L =4Ω to ∞
Diagnostic output delay time	t _{DLH}	_	320	640	μs	V _{DD} =5V,R _L =∞ to 4Ω
Open load detection threshold voltage ⁽¹⁾	VOPEN	1	2	3	V	IN=0V
Open load detection time	topen	100	300	900	μs	IN=0V

(1) To enable detection, an external resistance must be added between DRAIN terminal and SOURCE terminal. (Determine Rext depending on R_L .)



Definition

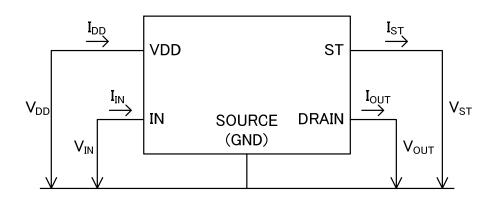


Figure 1. Definition

Measuring Circuit Diagram

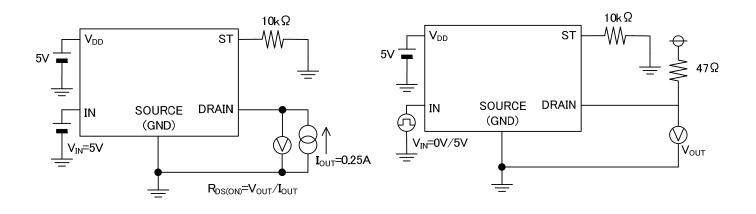


Figure 2. Output ON Resistance Measuring Circuit Diagram

Figure 3. Switching Time Measuring Circuit Diagram

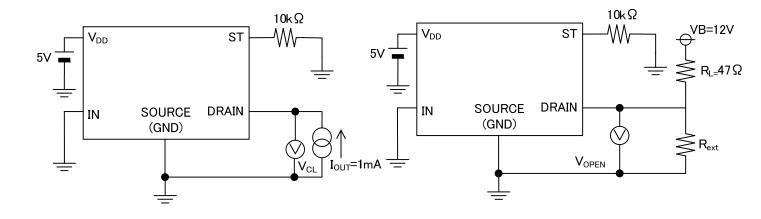
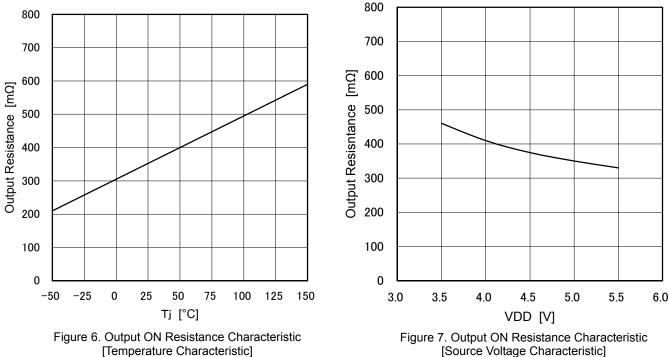


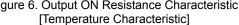
Figure 4. Output Clamp Voltage Measuring Circuit Diagram Figure 5. Open Detection Measuring Circuit Diagram

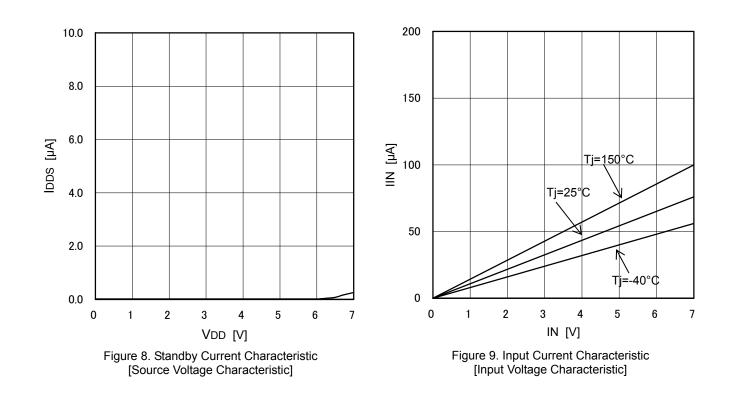
Diagnostic Output Truth Table

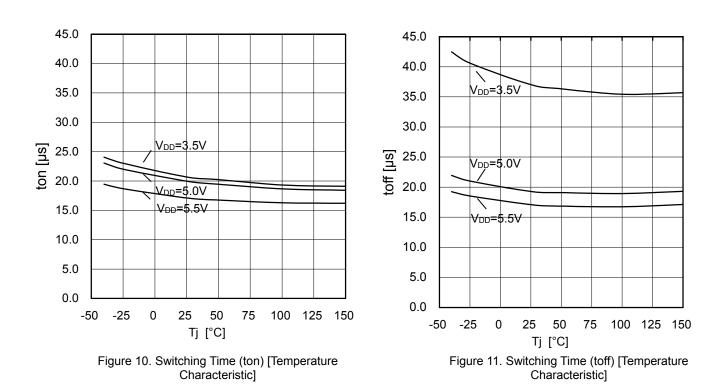
V	V _{IN} Tj	OU [.]	TPUT	Mode	Vst	Output state	
VIN		Vout	lout	Mode	VSI	Oulpul state	
	Tj ≤175°C(Typ) H		Іоит < 1.5А(Тур)	Normal	Н	ON	
н				Overcurrent detection	L	OFF	
	Tj >175°C(Typ)	-	-	Thermal shut down	L	OFF	
		H (3.0V or more)	-	Normal	Н	OFF	
		- L (2.0V(Typ) or less)		-	Open load protection	L	OFF

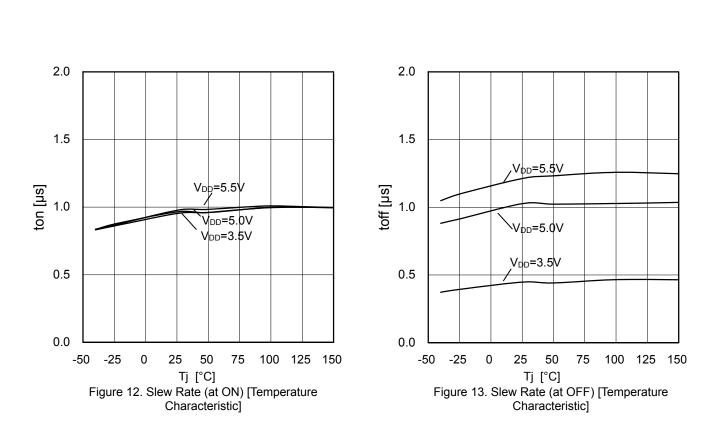
Characteristic Data (Reference Data) (V_{DD}=5V, IN=5V, Tj=25°C unless otherwise is specified)



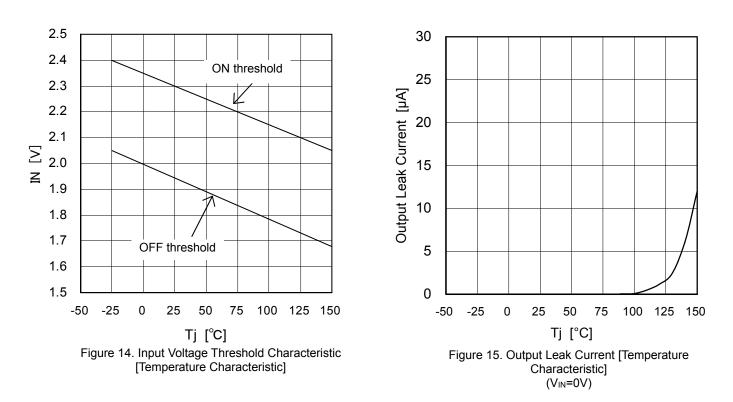








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Switching Time Measurement

Timing Chart with Inductive Load

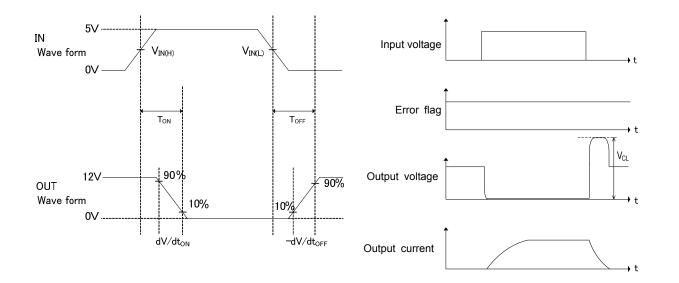


Figure 16. Switching Time

Figure 17. Timing Chart with Inductive Load

Protective Function Timing Charts

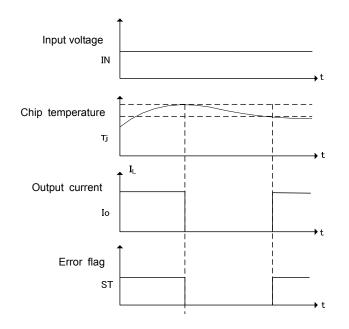


Figure 18. Overheat Protection Timing Chart

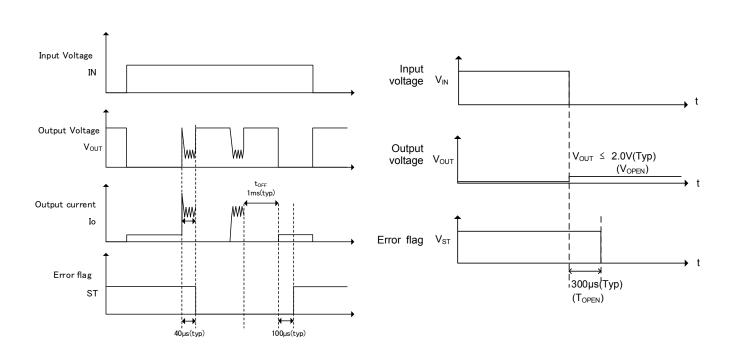
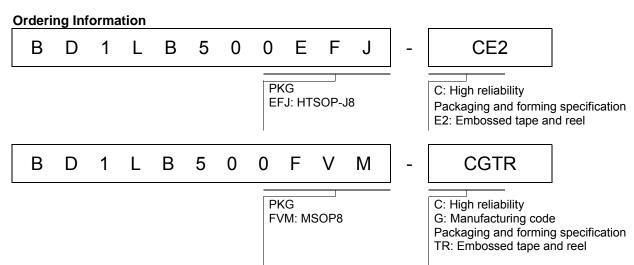


Figure 19. Overcurrent Protection Timing Chart

Figure 20. Open Detection Protection Timing Chart

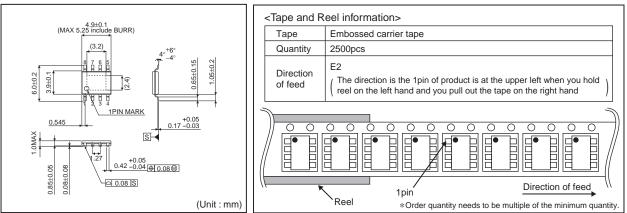
I/O Equivalent Circuits

I/O Equivalent C	ircuits	
Pin	Symbol	I/O Equivalent Circuits
1	IN	NN SOURCE GND SOURCE
2	ST	VDD X VDD X SOURCE (GND) X
3.4	SOURCE (GND)	
5,6	DRAIN	DRAIN DRAIN DRAIN SOURCE (GND)
8	VDD	
Cooling Tab	TAB	

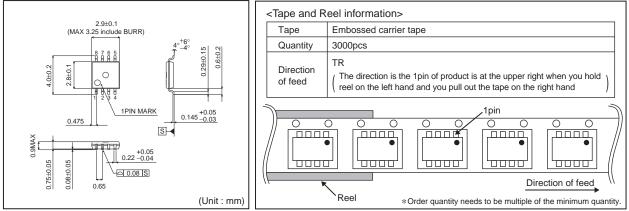


Physical Dimension Tape and Reel Information

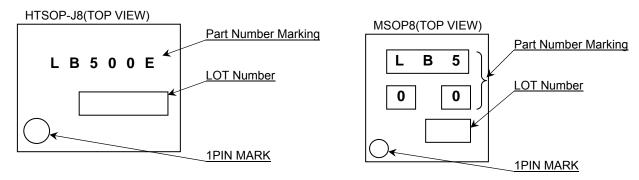
HTSOP-J8



MSOP8



Marking Diagram



Operational Notes

1) Absolute Maximum Ratings

Operating the IC over the absolute maximum ratings may damage the IC. In addition, it is impossible to predict all destructive situations such as short-circuit modes or open circuit modes. Therefore, it is important to consider circuit protection measures, like adding a fuse, in case the IC is expected to be operated in a special mode exceeding the absolute maximum ratings.

2) Reverse connection of power supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply terminals.

3) Power supply lines

Design the PCB layout pattern to provide low impedance ground and supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

4) Source (GND) Voltage

The voltage of the Source (GND) pin must be the lowest voltage of all pins of the IC at all operating conditions. Ensure that no pins are at a voltage below the ground pin at any time, even during transient condition.

5) Thermal consideration

Use a thermal design that allows for a sufficient margin by taking into account the permissible power dissipation (Pd) in actual operating conditions. Consider Pc that does not exceed Pd in actual operating conditions (Pc≥Pd).

Package Power dissipation : Pd (W)=(Tjmax-Ta)/ θ ja Power dissipation : Pc (W)=(Vcc-Vo)×Io+Vcc×Ib

Tjmax : Maximum junction temperature=150°C, Ta : Peripheral temperature[°C], θ ja : Thermal resistance of package-ambience[°C/W], Pd : Package Power dissipation [W], Pc : Power dissipation [W], Vcc : Input Voltage, Vo : Output Voltage, Io : Load, Ib : Bias Current

6) Short between pins and mounting errors

Be careful when mounting the IC on printed circuit boards. The IC may be damaged if it is mounted in a wrong orientation or if pins are shorted together. Short circuit may be caused by conductive particles caught between the pins.

7) Thermal shutdown circuit (TSD)

The IC incorporates a built-in thermal shutdown circuit, which is designed to turn off the IC when the internal temperature of the IC reaches 175°C (25°C hysteresis). It is not designed to protect the IC from damage or guarantee its operation. Do not continue to operate the IC after this function is activated. Do not use the IC in conditions where this function will always be activated.

8) Over voltage protection (active clamp)

There is a built-in over voltage protection circuit (active clamp) to absorb the induced current when inductive load is off (Power MOS = off). During active clamp and when IN=0V, TSD will not function so keep IC temperature below 150°C.

9) Over current protection circuit (OCP)

The IC incorporates an over-current protection circuit that operates in accordance with the rated output capacity. This circuit protects the IC from damage when the load becomes shorted. It is also designed to limit the output current (without latching) in the event of more than 1.5A (typ) flow, such as from a large capacitor or other component connected to the output pin. This protection circuit is effective in preventing damage to the IC in cases of sudden and unexpected current surges. The IC should not be used in applications where the over current protection circuit will be activated continuously.

10) Testing on application boards

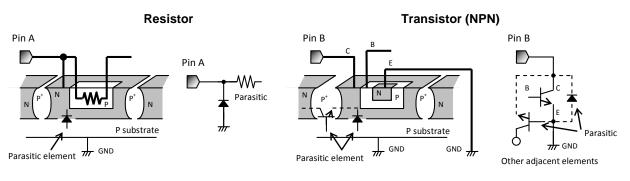
When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

11) Regarding input pins of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.



Example of monolithic IC structure

12) GND wiring pattern

When using both small-signal and large-current GND traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the GND traces of external components do not cause variations on the GND voltage. The power supply and ground lines must be as short and thick as possible to reduce line impedance.

13) Back electromotive force (BEMF)

There is a possibility that the BEMF is changed by using the operating condition, environment and the individual characteristics of motor. Please make sure there is no problem when operating the IC even though the BEMF is changed.

14) Rush Current

When power is supplied to the IC, inrush current may flow instantaneously. It is possible that the charge current from the parasitic capacitance of the internal logic may be unstable. Therefore, give a special consideration with the power coupling capacitance, power wiring, width of GND wiring, and routing of connections.

15) TAB

IC' sub is already connected to TAB, please short TAB to External GND.

Revision History

Date	Revision	Changes				
01.Aug.2013	003	New release				
06.Aug.2013	004	P.11 Figure20 V _{OUT} timing chart is modified.				
10.Jan.2014	005	 P4. Condition of Diagnostic output voltage "L level" is added. P4. Item of Diagnostic output voltage "H level" is added. 				
1.Apr.2015	006	 P1. "AEC-Q100 qualified" is added in Features P1. Note (1),(2) and (3) are added P2. Pin No 7 N.C. is added in Pin Description P2. "Cooling Tab" (Symbol; TAB) is added in Pin Description P3. Note (6) is added P4. Min of "Diagnostic output voltage "H level" " is changed to 4.88V P9. "ton" is changed to "toff" in Figure 11. 13. P10. Figure 17 is changed P15. FIN is changed to TAB in 15) 				
10.Nov.2015	007	 P3. "Absolute Maximum Ratings" Note (5) is changed P3. "Heat Dissipation Characteristics" Note(3) is changed 				
26.May.2017	008	 P1. "Basic Application Circuit(Recommendation)" Comment of note (3) is added P3. Active clamp energy (single pulse) limit value of Tj(0)=150°C is added in "Absolute Maximum Ratings". P13. Revised expression on the information of Ordering Information. 				

Notice

Precaution on using ROHM Products

1. If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment ^(Note 1), aircraft/spacecraft, nuclear power controllers, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

JAPAN	USA	EU	CHINA
CLASSI	CLASSⅢ	CLASS II b	CLASSII
CLASSⅣ	CLASSI	CLASSⅢ	CLASSII

2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:

[a] Installation of protection circuits or other protective devices to improve system safety

[b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure

- 3. Our Products are not designed under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
 - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

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